NSN 5961-01-014-8151Diode Semiconductor Device - Page 1 of 1



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nclosure Material:
Glass
Overall Length:
Between 0.150 inches and 0.275 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.068 inches and 0.105 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
0.5 on voltage, forward voltage drop, dc
Current Rating Per Characteristic:
1.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
100.0 milliwatts small-signal input power, common-collector absolute
Test Data Document:
30003-247as-c1235 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0